# 8-Input Multiplexer with 3-State Outputs

The TTL/MSI SN74LS251 is a high speed 8-Input Digital Multiplexer. It provides, in one package, the ability to select one bit of data from up to eight sources. The LS251 can be used as a universal function generator to generate any logic function of four variables. Both assertion and negation outputs are provided.

- Schottky Process for High Speed
- Multifunction Capability
- On-Chip Select Logic Decoding
- Inverting and Non-Inverting 3-State Outputs
- Input Clamp Diodes Limit High Speed Termination Effects

# **GUARANTEED OPERATING RANGES**

Symbol	Parameter	Min	Тур	Max	Unit
V <sub>CC</sub>	Supply Voltage	4.75	5.0	5.25	V
T <sub>A</sub>	Operating Ambient Temperature Range	0	25	70	°C
I <sub>OH</sub>	Output Current – High			-2.6	mA
I <sub>OL</sub>	Output Current – Low			24	mA



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LOW POWER SCHOTTKY



PLASTIC N SUFFIX CASE 648

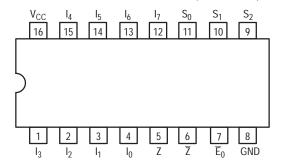


SOIC D SUFFIX CASE 751B

#### **ORDERING INFORMATION**

Device	Package	Shipping		
SN74LS251N	16 Pin DIP	2000 Units/Box		
SN74LS251D	16 Pin	2500/Tape & Reel		

# CONNECTION DIAGRAM DIP (TOP VIEW)

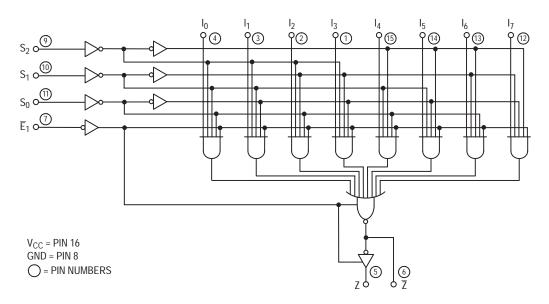


		LOADING (Note a)		
PIN NAMES		HIGH	LOW	
$S_0 - S_2$ $\overline{E}_0$ $I_0 - I_7$ $Z$ $\overline{Z}$	Select Inputs Output Enable (Active LOW) Inputs Multiplexer Inputs Multiplexer Output Complementary Multiplexer Output	0.5 U.L. 0.5 U.L. 0.5 U.L. 65 U.L. 65 U.L.	0.25 U.L. 0.25 U.L. 0.25 U.L. 15 U.L. 15 U.L.	

NOTES:

a) 1 TTL Unit Load (U.L.) = 40  $\mu$ A HIGH/1.6 mA LOW.

# LOGIC DIAGRAM



#### **FUNCTIONAL DESCRIPTION**

The LS251 is a logical implementation of a single pole, 8-position switch with the switch position controlled by the state of three Select inputs,  $S_0$ ,  $S_1$ ,  $S_2$ . Both assertion and negation outputs are provided. The Output Enable input  $(\overline{E}_O)$  is active LOW. When it is activated, the logic function provided at the output is:

$$\begin{split} Z &= \overline{E}_O \cdot (I_O \cdot \overline{S}_O \cdot \overline{S}_1 \cdot \overline{S}_2 + I_1 \cdot S_O \cdot \overline{S}_1 \cdot \overline{S}_2 + I_2 \cdot \overline{S}_O \cdot S_1 \cdot \\ & \overline{S}_2 + I_3 \cdot S_O \cdot S_1 \cdot \overline{S}_2 + I_4 \cdot \overline{S}_O \cdot \overline{S}_1 \cdot S_2 + I_5 \cdot S_O \cdot \\ & \overline{S}_1 \cdot S_2 + I_6 \cdot \overline{S}_O \cdot S_1 \cdot S_2 + I_7 \cdot S_O \cdot S_1 \cdot S_2). \end{split}$$

When the Output Enable is HIGH, both outputs are in the high impedance (high Z) state. This feature allows multiplexer expansion by tying the outputs of up to 128 devices together. When the outputs of the 3-state devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. The Output Enable signals should be designed to ensure there is no overlap in the active LOW portion of the enable voltage.

#### **TRUTH TABLE**

Ē₀	S <sub>2</sub>	S <sub>1</sub>	S <sub>0</sub>	I <sub>0</sub>	I <sub>1</sub>	l <sub>2</sub>	l <sub>3</sub>	I <sub>4</sub>	l <sub>5</sub>	I <sub>6</sub>	I <sub>7</sub>	Z	Z
Н	Х	Χ	Χ	Х	Χ	Χ	Χ	Х	Χ	Χ	Χ	(Z)	(Z)
L	L	L	L	L	Χ	Χ	Χ	Χ	X	X	X	Н	L
L	L	L	L	Н	Χ	Χ	Χ	Χ	X	X	X	L	Н
L	L	L	Н	Х	L	Χ	Χ	Χ	X	X	X	Н	L
L	L	L	Н	Х	Н	Χ	Χ	Χ	Χ	X	X	L	Н
L	L	Н	L	Х	Χ	L	Χ	Χ	X	X	X	Н	L
L	L	Н	L	Х	Χ	Н	Χ	Χ	X	X	X	L	Н
L	L	Н	Н	Х	Χ	Χ	L	Χ	X	X	X	Н	L
L	L	Н	Н	Х	Χ	Χ	Н	Χ	X	Χ	X	L	Н
L	Н	L	L	Х	Χ	Χ	Χ	L	X	X	X	Н	L
L	Н	L	L	Х	Χ	Χ	Χ	Н	X	X	X	L	Н
L	Н	L	Н	Х	Χ	Χ	Χ	Χ	L	Χ	X	Н	L
L	Н	L	Н	Х	Χ	Χ	Χ	Χ	Н	X	X	L	Н
L	Н	Н	L	Х	Χ	Χ	Χ	Χ	Χ	L	X	Н	L
L	Н	Н	L	Х	Χ	Χ	Χ	Χ	X	Н	X	L	Н
L	Н	Н	Н	Х	Χ	Χ	X	X	X	Χ	L	Н	L
L	Н	Н	Н	Х	Χ	Χ	Χ	Χ	Χ	Χ	Н	L	Н

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

<sup>(</sup>Z) = High impedance (Off)

# DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	<b>Test Conditions</b>		
V <sub>IH</sub>	Input HIGH Voltage	2.0			V	Guaranteed Inpu All Inputs	t HIGH Voltage for	
V <sub>IL</sub>	Input LOW Voltage			0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for	
V <sub>IK</sub>	Input Clamp Diode Voltage		-0.65	-1.5	V	V <sub>CC</sub> = MIN, I <sub>IN</sub> =	–18 mA	
V <sub>OH</sub>	Output HIGH Voltage	2.4	3.1		V	$V_{CC}$ = MIN, $I_{OH}$ = MAX, $V_{IN}$ = $V_{IH}$ or $V_{IL}$ per Truth Table		
.,			0.25	0.4	٧	I <sub>OL</sub> = 12 mA	$V_{CC} = V_{CC} MIN,$	
V <sub>OL</sub>	Output LOW Voltage		0.35	0.5	V	I <sub>OL</sub> = 24 mA	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> per Truth Table	
I <sub>OZH</sub>	Output Off Current HIGH			20	μА	V <sub>CC</sub> = MAX, V <sub>OUT</sub> = 2.7 V		
I <sub>OZL</sub>	Output Off Current LOW			-20	μА	$V_{CC} = MAX, V_{OU}$	T = 0.4 V	
	Innut HICH Current			20	μА	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 2.7 V		
IН	Input HIGH Current			0.1	mA	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 7.0 V		
I <sub>IL</sub>	Input LOW Current			-0.4	mA	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 0.4 V		
I <sub>OS</sub>	Short Circuit Current (Note 1)	-30		-130	mA	V <sub>CC</sub> = MAX		
	Dawer Cumply Current			10	mA	$V_{CC} = MAX, V_E^- = 0 V$		
I <sub>CC</sub>	Power Supply Current			12	mA	$V_{CC} = MAX, V_{E}^{-} = 4.5 V$		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

# AC CHARACTERISTICS ( $T_A = 25^{\circ}C$ , $V_{CC} = 5.0 \text{ V}$ )

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test	Conditions	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay, Select to ℤ Output		20 21	33 33	ns	Figure 1		
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay, Select to Z Output		29 28	45 45	ns	Figure 2		
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay, Data to Z Output		10 9.0	15 15	ns	Figure 1	C <sub>L</sub> = 15 pF,	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay, Data to Z Output		17 18	28 28	ns	Figures 2	$R_L = 2.0 \text{ k}\Omega$	
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time to Z Output		17 24	27 40	ns	Figures 4, 5		
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time to Z Output		30 26	45 40	ns	Figures 3, 5		
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time to Z Output		37 15	55 25	ns	Figures 3, 5	$C_{L} = 5.0  pF,$	
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time to Z Output		30 15	45 25	ns	Figures 4, 5	$R_L = 667 \text{ k}\Omega$	

# **3-STATE AC WAVEFORMS**

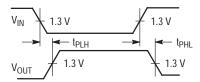


Figure 1.

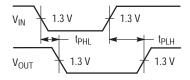


Figure 2.

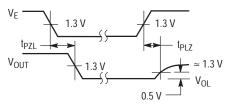


Figure 3.

0.5 V

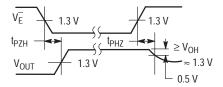


Figure 4.

# **AC LOAD CIRCUIT**

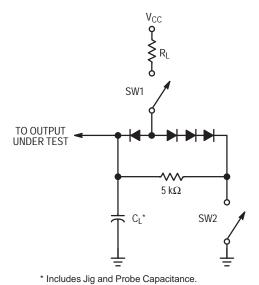


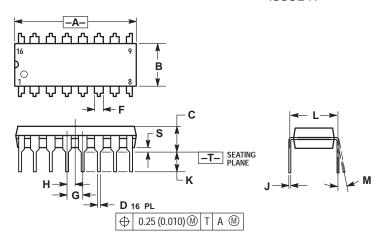
Figure 5.

# **SWITCH POSITIONS**

SYMBOL	SW1	SW2
t <sub>PZH</sub>	Open	Closed
$t_{PZL}$	Closed	Open
$t_{PLZ}$	Closed	Closed
t <sub>PHZ</sub>	Closed	Closed

# **PACKAGE DIMENSIONS**

# **N SUFFIX** PLASTIC PACKAGE CASE 648-08 ISSUE R

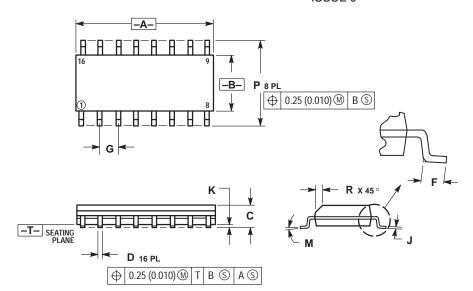


- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
  4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
  5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
M	0°	10 °	0°	10 °	
S	0.020	0.040	0.51	1.01	

# **PACKAGE DIMENSIONS**

# **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751B-05 **ISSUE J**



#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETER.

  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN MAX		MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7°	0 °	7°
Р	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

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